

Dimensions SOT-23



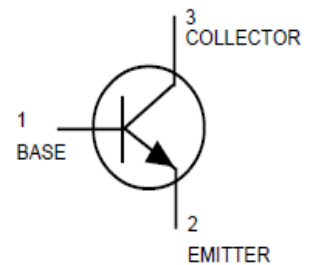
●FEATURES

- 1) We declare that the material of product compliant with RoHS requirements and Halogen Free.
- 2) S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

●DEVICE MARKING AND ORDERING INFORMATION

| Device | Marking | Shipping |
|----------|---------|----------------|
| MMBT4401 | 2X | 3000/Tape&Reel |

Pin Configuration



●MAXIMUM RATINGS(Ta = 25°C)

| Parameter | Symbol | Limits | Unit |
|--------------------------------|------------------|--------|------|
| Collector–Emitter Voltage | V _{CEO} | 40 | Vdc |
| Collector–Base Voltage | V _{CBO} | 60 | Vdc |
| Emitter–Base Voltage | V _{EB0} | 6 | Vdc |
| Collector Current — Continuous | I _C | 600 | mAdc |

●THERMAL CHARACTERISTICS

| | | | |
|--|----------------------------------|------------|-------------|
| Total Device Dissipation, FR–5 Board (Note 1) @ T _A = 25°C Derate above 25°C | P _D | 225 1.8 | mW mW/°C |
| Thermal Resistance, Junction–to–Ambient(Note 1) | R _{θJA} | 556 | °C/W |
| Total Device Dissipation, Alumina Substrate (Note 2) @ T _A = 25°C Derate above 25°C | P _D | 300 2.4 | mW mW/°C |
| Thermal Resistance, Junction–to–Ambient(Note 2) | R _{θJA} | 417 | °C/W |
| Junction and Storage temperature | T _J ,T _{stg} | –55 ~ +150 | °C |

1. FR–5 = 1.0×0.75×0.062 in.

2. Alumina = 0.4×0.3×0.024 in. 99.5% alumina.



● ELECTRICAL CHARACTERISTICS (Ta= 25°C)

OFF CHARACTERISTICS

| Characteristic | Symbol | Min. | Typ. | Max. | Unit |
|---|----------------------|------|------|------|------|
| Collector–Emitter Breakdown Voltage (I _C = 1.0 mA _{dc} , I _B = 0) | V _{BR(CEO)} | 40 | – | – | V |
| Collector–Base Breakdown Voltage (I _C = 0.1mA _{dc} , I _E = 0) | V _{BR(CBO)} | 60 | – | – | V |
| Emitter–Base Breakdown Voltage (I _E = 0.1mA _{dc} , I _C = 0) | V _{BR(EBO)} | 6 | – | – | V |
| Collector Cutoff Current (V _{CE} = 35 Vdc, V _{EB} = 0.4Vdc) | I _{CEX} | – | – | 0.1 | μA |
| Base Cutoff Current (V _{CE} = 35 Vdc, V _{EB} = 0.4Vdc) | I _{BEV} | – | – | 0.1 | μA |

ON CHARACTERISTICS (Note 3.)

| | | | | | |
|---|----------------------|-----------------------------|-----------------------|-------------------------|---|
| DC Current Gain (I _C = 0.1 mA _{dc} , V _{CE} = 1.0 Vdc) (I _C = 1.0 mA _{dc} , V _{CE} = 1.0 Vdc) (I _C = 10 mA _{dc} , V _{CE} = 1.0 Vdc) (I _C = 150 mA _{dc} , V _{CE} = 1.0 Vdc) (I _C = 500 mA _{dc} , V _{CE} = 2.0 Vdc) | h _{FE} | 20 40 80 100 40 | – – – – – | – – – 300 – | |
| Collector–Emitter Saturation Voltage(3) (I _C = 150 mA _{dc} , I _B = 15 mA _{dc}) (I _C = 500mA _{dc} , I _B = 50 mA _{dc}) | V _{CE(sat)} | – – | – – | 0.4 0.75 | V |
| Base–Emitter Saturation Voltage (I _C = 150 mA _{dc} , I _B = 15 mA _{dc}) (I _C = 500mA _{dc} , I _B = 50 mA _{dc}) | V _{BE(sat)} | 0.75 – | – – | 0.95 1.2 | V |

SMALL–SIGNAL CHARACTERISTICS

| Characteristic | Symbol | Min. | Typ. | Max. | Unit |
|---|-----------------|------|------|------|--------------------|
| Current–Gain — Bandwidth Product (I _C = 20mA _{dc} , V _{CE} = 20Vdc, f = 100MHz) | f _T | 250 | – | – | MHz |
| Collector–Base Capacitance (V _{CB} = 5.0 Vdc, I _E = 0, f = 1.0 MHz) | C _{cb} | – | – | 6.5 | pF |
| Emitter–Base Capacitance (V _{EB} = 0.5 Vdc, I _C = 0, f = 1.0 MHz) | C _{eb} | – | – | 30 | pF |
| Input Impedance (V _{CE} = 10 Vdc, I _C = 1.0 mA _{dc} , f = 1.0 kHz) | h _{ie} | 1 | – | 15 | k Ω |
| Voltage Feedback Ratio (V _{CE} = 10 Vdc, I _C = 1.0 mA _{dc} , f = 1.0 kHz) | h _{re} | 0.1 | – | 8 | X 10 ⁻⁴ |
| Small–Signal Current Gain (V _{CE} = 10 Vdc, I _C = 1.0 mA _{dc} , f = 1.0 kHz) | h _{fe} | 40 | – | 500 | |
| Output Admittance (V _{CE} = 10 Vdc, I _C = 1.0 mA _{dc} , f = 1.0 kHz) | h _{oe} | 1 | – | 30 | μmhos |

SWITCHING CHARACTERISTICS

| | | | | | | |
|--------------|---|----------------|---|---|-----|----|
| Delay Time | (V _{CC} = 30 Vdc, V _{EB} = 2.0Vdc, I _C = 150 mA _{dc} , I _{B1} = 15 mA _{dc}) | t _d | – | – | 15 | ns |
| Rise Time | | t _r | – | – | 20 | |
| Storage Time | | t _s | – | – | 225 | |
| Fall Time | | t _f | – | – | 30 | |

3. Pulse Test: Pulse Width <300 μs, Duty Cycle <2.0%.

ELRCTRICAL CHARACTERISTICS CURVES

SWITCHING TIME EQUIVALENT TEST CIRCUITS

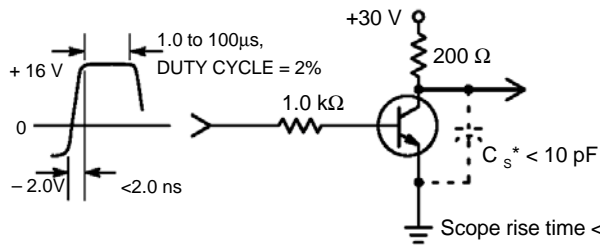


Figure 1. Turn-On Time

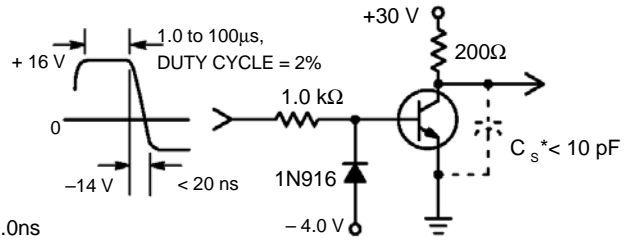


Figure 2. Turn-Off Time

*Total shunt capacitance of test jig connectors, and oscilloscope

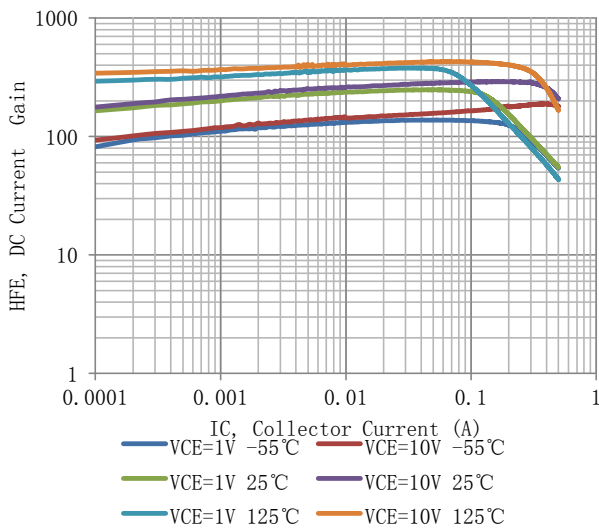


Figure 3. DC Current Gain

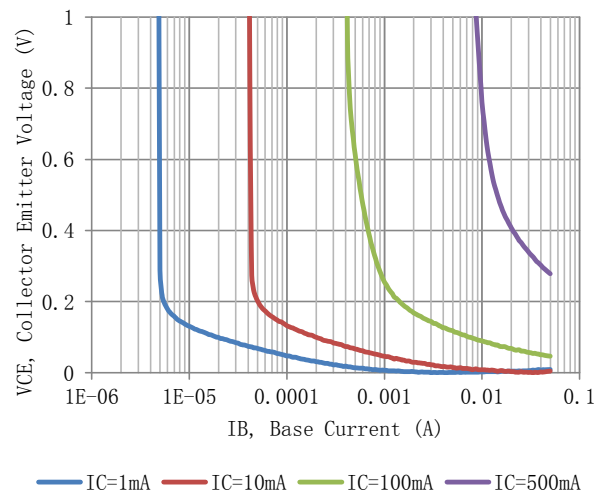


Figure 4. Collector Saturation Region

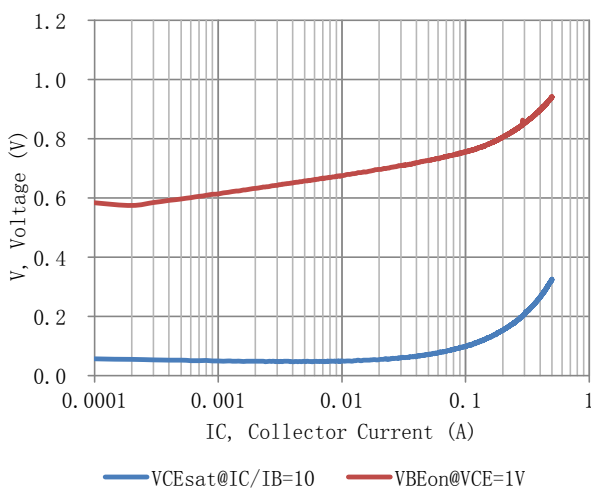


Figure 5. "On" Voltage

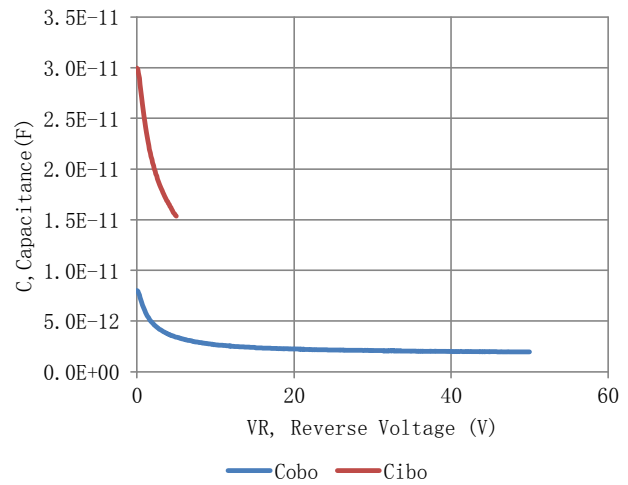


Figure 6. Capacitance

ELECTRICAL CHARACTERISTICS CURVES

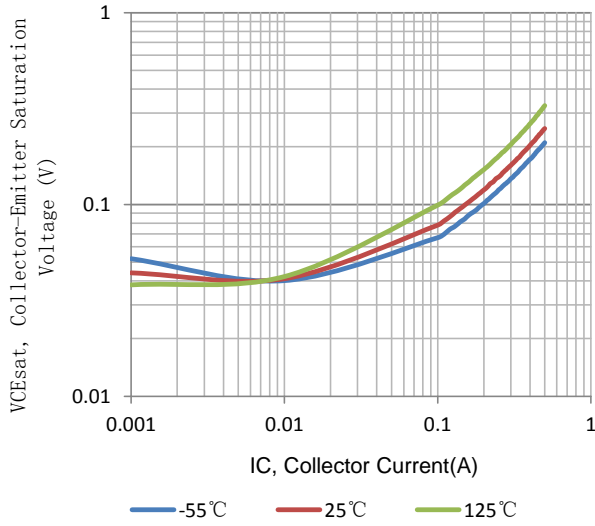


Figure 7. Collector-Emitter Saturation Voltage vs. Collector Current

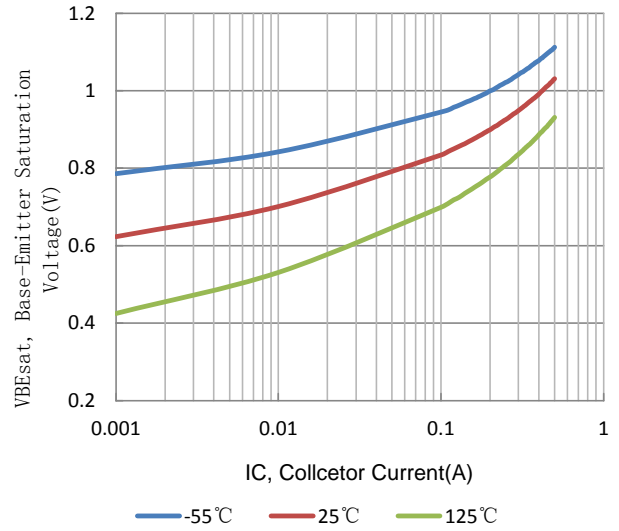


Figure 8. Base-Emitter Saturation Voltage vs. Collector Current

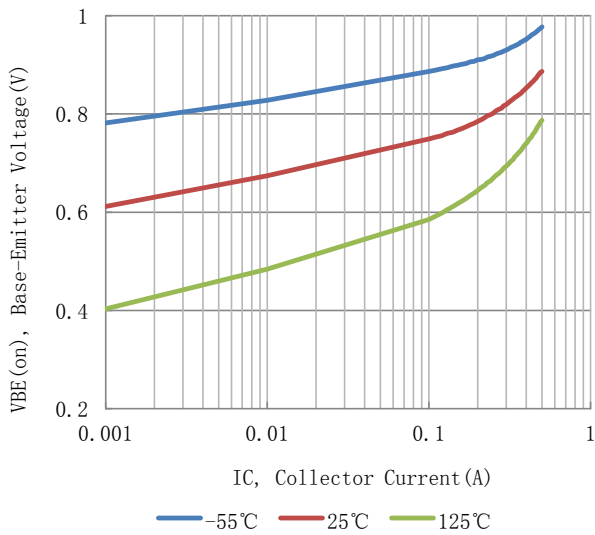
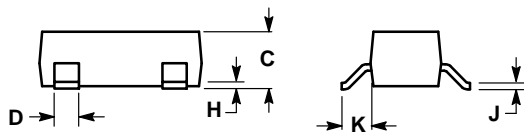
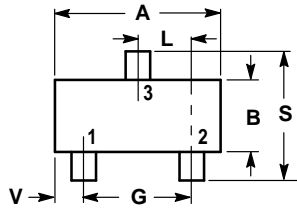


Figure 9. Base-Emitter Voltage vs. Collector Current

SOT-23



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

| DIM | INCHES | | MILLIMETERS | |
|-----|--------|--------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 0.1102 | 0.1197 | 2.80 | 3.04 |
| B | 0.0472 | 0.0551 | 1.20 | 1.40 |
| C | 0.0350 | 0.0440 | 0.89 | 1.11 |
| D | 0.0150 | 0.0200 | 0.37 | 0.50 |
| G | 0.0701 | 0.0807 | 1.78 | 2.04 |
| H | 0.0005 | 0.0040 | 0.013 | 0.100 |
| J | 0.0034 | 0.0070 | 0.085 | 0.177 |
| K | 0.0140 | 0.0285 | 0.35 | 0.69 |
| L | 0.0350 | 0.0401 | 0.89 | 1.02 |
| S | 0.0830 | 0.1039 | 2.10 | 2.64 |
| V | 0.0177 | 0.0236 | 0.45 | 0.60 |

- PIN 1. BASE
 2. EMITTER
 3. COLLECTOR

